Preferred Device

Silicon Pin Diode

This device is designed primarily for VHF band switching applications but is also suitable for use in general–purpose switching circuits. Supplied in a Surface Mount package.

- Rugged PIN Structure Coupled with Wirebond Construction for Optimum Reliability
- Low Capacitance 0.7 pF Typ at $V_R = 20$ Vdc
- Very Low Series Resistance at 100 MHz 0.34 Ohms (Typ) @ $I_F = 10$ mAdc
- Device Marking: 4D



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SILICON PIN SWITCHING DIODE

MAXIMUM RATINGS

Symbol	Rating	Value	Unit
VR	Continuous Reverse Voltage	20	Vdc
١ _F	Peak Forward Current	20	mAdc

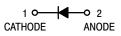
THERMAL CHARACTERISTICS

Symbol	Characteristic	Max	Unit
PD	Total Device Dissipation FR–5 Board,* T _A = 25°C Derate above 25°C	200 1.57	mW mW/°C
$R_{\theta JA}$	Thermal Resistance Junction to Ambient	635	°C/W
TJ, Tstg	Junction and Storage Temperature	150	°C

*FR-4 Minimum Pad



PLASTIC SOD-323 CASE 477



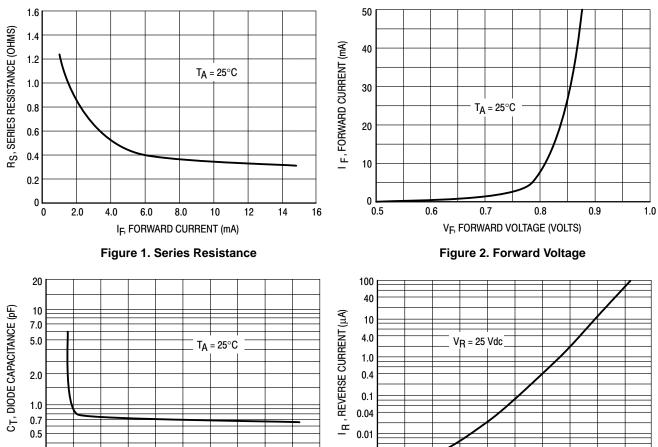
ORDERING INFORMATION

Device	ice Package Shipping	
MMVL3401T1	SOD-323	3000 / Tape & Reel

Preferred devices are recommended choices for future use and best overall value.

ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit
Reverse Breakdown Voltage (I _R = 10 μAdc)	V _{(BR)R}	35	—	—	Vdc
Diode Capacitance (V _R = 20 Vdc)	CT	—	_	1.0	pF
Series Resistance (Figure 5) (I _F = 10 mAdc, f = 100 MHz)	RS	—	_	0.7	Ω
Reverse Leakage Current (V _R = 25 Vdc)	۱ _R	_	_	0.1	μAdc

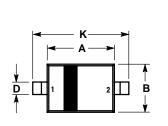


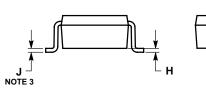
TYPICAL CHARACTERISTICS

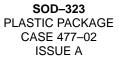
0.004 0.2 L +3.0 0.001 -6.0 -9.0 -12 -15 -18 -21 -24 0 -3.0 -27 -60 -20 0 +20 +60 +100 VR, REVERSE VOLTAGE (VOLTS) T_A, AMBIENT TEMPERATURE (°C) Figure 3. Diode Capacitance Figure 4. Leakage Current

+140

PACKAGE DIMENSIONS







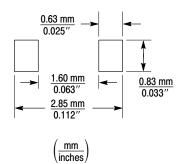
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NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: MILLIMETERS. 3. LEAD THICKNESS SPECIFIED PER L/F DRAWING WITH SOLDER PLATING.

	MILLIMETERS		INCHES		
DIM	MIN	MAX	MIN	MAX	
Α	1.60	1.80	0.063	0.071	
В	1.15	1.35	0.045	0.053	
С	0.80	1.00	0.031	0.039	
D	0.25	0.40	0.010	0.016	
Е	0.15 REF		0.006 REF		
Η	0.00	0.10	0.000	0.004	
J	0.089	0.177	0.0035	0.0070	
Κ	2.30	2.70	0.091	0.106	

STYLE 1: PIN 1. CATHODE 2. ANODE



SOD-323 Soldering Footprint

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